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Frequency Comb Assisted Broadband Precision Spectroscopy with Cascaded Diode Lasers

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Frequency comb assisted diode laser spectroscopy, employing both the accuracy of an optical frequency comb and the broad wavelength tuning range of a tunable diode laser, has been widely used in many applications. In this letter we present a novel method using cascaded frequency agile diode lasers, which allows extending the measurement bandwidth to 37.4 THz (1355 – 1630 nm) at MHz resolution with scanning speeds above 1 THz/s. It is demonstrated as a useful tool to characterize a broadband spectrum for molecular spectroscopy and in particular it enables to characterize the dispersion of integrated microresonators up to the fourth order.

The dispersion characterization is important for the dispersion engineering of integrated high-Q microresonators for Kerr frequency comb generation [22, 23] and bright dissipative Kerr soliton formation [24–27]. In addition, properly engineered higher order dispersion can lead to the emission of a dispersive wave via the process of soliton Cherenkov radiation [27–29]. Several techniques based on geometry variation [31] and additional material layers [13, 32] have been demonstrated to tailor the dispersion. However, to measure the higher order dispersion of microresonators, frequency comb assisted diode laser spectroscopy is currently limited by its measurement bandwidth, which is mainly determined by the wavelength tuning range of the used laser. Therefore, using more than one laser to cover different spectral ranges is desired to overcome the bandwidth limitation thus enabling measuring the higher order dispersion. In this letter we demonstrate a method to extend the measurement bandwidth by cascading two widely tunable lasers covering the wavelength range from 1355 nm to 1630 nm. The validity of our method is examined by molecular absorption spectroscopy. We subsequently use this method to characterize the dispersion of a photonic chip-based silicon nitride (Si3N4) microresonator [33] whose FSR is approximately 1 THz. This is the first time that higher order dispersion is directly measured for such microresonators.

The experimental setup is shown in Fig. 1 and is based on the setup described in Ref. [6]. Two widely tunable mode-hop-free external cavity diode lasers (ECDL 1, ECDL 2, Santec TSL-510) with wavelength tuning ranges of 1355 – 1505 nm and 1500 – 1630 nm beat with a fully-stabilized spectrally broadened erbium-doped-fiber-laser-based frequency comb (MenloSystems FC1500, repetition
rate $f_{\text{rep}} \approx 250$ MHz, range 1050 – 2100 nm). A 1310 nm/1550 nm wavelength-division multiplexer (WDM) splits the frequency comb into two branches. Two optical switches are synchronized, such that ECDL 1 beats with the 1310 nm branch, and successively ECDL 2 beats with the 1550 nm branch. The purpose of using the WDM and synchronizing the optical switches is to suppress the comb lines which do not contribute to the beat signals, thus to prevent the photodiode saturation and to improve the signal-to-noise ratio of the beat signals.

The two ECDLs scan one after the other with a scan speed of 10 nm/s. By using the band-pass filters labeled as BP 1, BP 2 (center frequencies $f_{\text{BP1}}, f_{\text{BP2}}$), the scanning ECDL generates four “calibration markers” per $f_{\text{rep}}$ interval when the frequency distance to its nearest comb line is $\pm f_{\text{BP1}}$ or $\pm f_{\text{BP2}}$ [6]. The key problem is the combination of the two individual traces generated by the two ECDL scans into a single continuous trace which covers the full measurement range. This is solved by using an auxiliary reference laser whose wavelength $\lambda_{\text{ref}}$ is set in the 1500 – 1505 nm range where both ECDLs overlap spectrally. With a low-pass filter (BP 3), in each trace a “reference marker” is recorded when the ECDL scans over the reference laser. The reference laser is set initially $f_{\text{rep}}/2$ from its nearest comb line, and its long-term drift is measured as <20 MHz/h as shown in Fig. 2(b). As long as the reference laser drifts less than $f_{\text{rep}}/2$ from its initial position within the measurement time ($\approx 60$ s), which can be monitored by an electrical spectrum analyzer (ESA), we can unambiguously assume that the calibration markers adjacent to the reference marker are generated by the same comb line in both traces. Therefore, using the reference marker, the indices of the calibration markers in both traces can be matched. As shown in Fig. 2(a), by combining the data before the reference marker in trace 1 with the data after the reference marker in trace 2, a complete continuous trace from 1355 nm to 1630 nm is formed.

Generally to combine individual traces into a single trace, it is required that: (1) each ECDL scans mode-hop-free; (2) any two adjacent ECDLs have a shared wavelength range; (3) a low-drift stable reference laser exists whose wavelength falls in each shared wavelength range; (4) calibration markers are well-resolved in each trace. Once the above conditions are satisfied, such setup can be extended with more than two ECDLs, enabling even
FIG. 4. Broadband dispersion characterization of a Si$_3$N$_4$ photonic chip-based microresonator with approximately 1 THz FSR. (a) SEM picture of the used microresonator geometry. (b) Linewidth difference between TM$_{00}$ and TM$_{10}$ modes. (c) Normalized transmission spectrum through the microresonator. (d) Plot of $D_{int}/2\pi$ of the TM$_{00}$ mode. Red points are the measured data, green solid curve is the 3rd order weighted fitting polynomial, blue solid curve is the 4th order weighted fitting polynomial. Different optical fiber communication bands are denoted by different color shaded zones. (e) Plot of the fitted linewidths of the TM$_{00}$ mode.

broader measurement bandwidth.

The reference laser sets the frequency reference point, and the frequency axis is calibrated with respect to the frequency comb based on $f_{\text{rep}}$. Assuming that the ECDLs scan uniformly in each $f_{\text{rep}}$ interval, the instantaneous frequency can be interpolated with respect to $f_{\text{BP1}}$ and $f_{\text{BP2}}$. The precision of frequency determination is limited by a 2.2 MHz/point resolution limit due to the oscilloscope's maximum 10 million data points per trace, and the error due to the 2 MHz bandwidth of the BPs. Therefore the total error is estimated as 4.2 MHz/point. However such error will not be prominent for spectral features with >100 MHz linewidth, as the center frequency is usually obtained by line profile fitting whose precision is then limited by the signal quality, fitting function used, resonance splitting etc.

The reference laser’s wavelength $\lambda_{\text{ref}}$ is read from a wavelength meter with an imprecision of few picometers (corresponding frequency imprecision is few hundreds MHz). Such imprecision will introduce a global offset to the absolute frequency calibration, but will not affect the continuity of the trace combination and the relative frequency calibration with respect to $\lambda_{\text{ref}}$. The global offset (i.e. an absolute frequency measurement) is much less important for certain measurements such as the dispersion measurement of microresonators where the entire frequency scan needs to exhibit a precise relative frequency calibration, but not necessarily an absolute frequency calibration.

In order to examine the validity of our method, e.g. the continuity of the combined trace and the relative frequency calibration, we implemented a molecular absorption spectroscopy of a gas cell composed of water (H$_2$O), carbon monoxide (CO) and acetylene (C$_2$H$_2$), and compared it with the absorption line data from HITRAN online [34] (www.hitran.org). The normalized transmission spectrum is shown in Fig. 3(a) and the absorption lines for each kind of molecule are marked. As the spectroscopy is not Doppler-free, a Gaussian function is used to fit the Doppler broadening profile [35], and the linewidth distribution is shown in Fig. 3(b). The fitted line-center frequencies $f_{\text{fit}}$ are then compared with the known frequencies $f_{\text{HIT}}$ from HITRAN online, and a global offset $f_{\text{off}} \approx 100$ MHz is observed due to the reason mentioned above. Subtracting the global offset, the frequency deviations defined by $\delta = f_{\text{fit}} - f_{\text{HIT}} - f_{\text{off}}$ are plotted in Fig. 3(c). All the frequency deviations are distributed in a ±100 MHz range around 0 MHz, showing the continuity of the combined trace and a good global accuracy of the relative frequency calibration. As the CO lines suffer the least Doppler broadening effect due to the largest molecular mass of CO, their frequencies are more precisely fitted with smaller deviations. Therefore to examine the precision of the relative frequency calibration, we fit the deviation distribution of CO lines with a Gaussian distribution and a 13.6 MHz standard deviation is shown. It should be emphasized that the 13.6 MHz standard deviation is not due to the method itself, but mainly due to the GHz Doppler broadening and the resulting higher statistical fitting error in determining the line-center frequencies. To eliminate the Doppler broadening and to demonstrate better precision, a Doppler-free spectroscopy could be built [11, 12].

An important application of our method is to charac-

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<th>TABLE I. Fitted dispersion parameters</th>
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<tr>
<td>Parameter</td>
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<tr>
<td>$D_1/2\pi$</td>
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<td>$D_3/2\pi$</td>
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terize the dispersion of microresonators. In this context, dispersion describes the variation of the FSR over frequency. It can be expressed in a Taylor series in analogue to the fiber case as

$$\omega_\mu = \omega_0 + D_1 \mu + \frac{1}{2} D_2 \mu^2 + \frac{1}{6} D_3 \mu^3 + \frac{1}{24} D_4 \mu^4 + \ldots$$

$$= \omega_0 + D_1 \mu + D_{\text{int}}(\mu)$$

Here $\omega_\mu$ is the angular frequency of the $\mu$-th resonance relative to the reference resonance $\omega_0$. $D_1/2\pi$ corresponds to the FSR. A non-zero $D_2$ leads to a parabolic deviation from an equidistant $D_1$-spaced resonance grid. $D_{\text{int}}(\mu)$ is the integrated dispersion including all higher order dispersion parameters, showing the total deviation.

We measured the dispersion of a Si$_3$N$_4$ microresonator fabricated using the photonic Damascene process [17]. The microresonator has a radius of 23 $\mu$m (corresponding $D_1/2\pi \approx 1$ THz) and is coupled by a single-mode bus waveguide, as shown in Fig. 4(a). Both the fundamental transverse magnetic mode (TM$_{00}$) and a higher order mode (TM$_{10}$) of the microresonator are excited by the TM waveguide mode. Referred to the simulations, they can be distinguished due to the different FSRs and linewidths as shown in Fig. 4(b) and 4(c). Each resonance is fitted with the model derived in Ref. [36], and the center frequency and the linewidth are extracted. Fig. 4(d) plots the $D_{\text{int}}/2\pi$ of the TM$_{00}$ mode, directly showing a visible $D_3$ contribution. Both a 3rd order and a 4th order weighted polynomial are used to fit the $D_{\text{int}}/2\pi$, while the reference resonance $\omega_0/2\pi$ is chosen at 193.12 THz (1553.5 nm). The fit is performed by weighting each resonance according to the inverse of its linewidth, as the center frequencies of broader resonances are less precisely fitted. As shown in Fig. 4(d), the 4th order weighted polynomial shows better fitting than the 3rd order one, indicating the necessity to consider the fourth order dispersion parameter $D_4$ in the fit. The dispersion parameters extracted from the 4th order polynomial fit for both TM$_{00}$ and TM$_{10}$ modes are shown in Table. I.

Fig. 4(e) plots the fitted linewidths of the TM$_{00}$ mode. The global trend showing decreasing linewidth with increasing frequency is due to the fact that the waveguide-resonator external coupling strength is wavelength-dependent [37]. In addition, an avoided modal crossing [14, 15] is identified around 213 THz where both modes have approximately the same local resonance frequency. At such a modal crossing point, the resonances deviate from the fitted dispersion curve and a local linewidth broadening is observed.

In conclusion, we have presented a novel way to extend frequency comb assisted diode laser spectroscopy with cascaded lasers, enabling a full measurement bandwidth of 37.4 THz (1355 – 1630 nm) at MHz resolution with scanning speeds above 1 THz/s. We show potential applications for molecular spectroscopy and for the measurement of higher order dispersion in microresonators which we demonstrate here for the first time in a Si$_3$N$_4$ photonic chip-based microresonator. Furthermore the described cascaded laser spectroscopy can be extended with more lasers, enabling a further increase of the measurement bandwidth.

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